

Photointerrupter(Transmissive)

KODENSHI

KPI-210C

DESCRIPTION

The photointerrupter high-performance standard type KPI-210C combines a high-output GaAs IRED with a high sensitivity phototransistor.

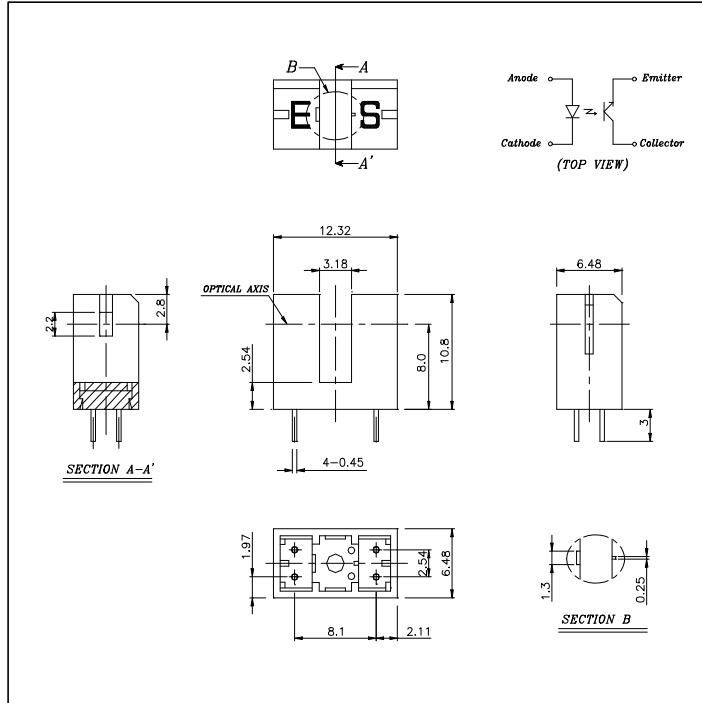
FEATURES

- High Performance
- GAP : 3.18mm
- High Speed Response
- Widely Applicable

APPLICATIONS

- Tape-end Sensor
- Timing Sensor
- Edge Sensor
- Copiers

DIMENSIONS



ABSOLUTE MAXIMUM RATINGS

(Ta=25 °C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I _F	60	mA
	Pulse Forward Current ^{*1}	I _{FP}	1	A
	Reverse Voltage	V _R	5	V
	Power Dissipation	P _D	100	mW
Output	Collector Emitter Voltage	V _{CEO}	30	V
	Emitter Collector Voltage	V _{ECD}	5	V
	Collector Current	I _C	40	mA
	Collector Power Dissipation	P _C	100	mW
Operating Temperature ^{*2}		T _{OPR}	-25 ~ +85	
Storage Temperature ^{*2}		T _{STG}	-40 ~ +85	
Soldering Temperature ^{*3}		T _{SOL}	260	

*1. Pulse width : tw 100usec. period : T=10msec

*2. No icebound or dew

*3. For MAX. 5 seconds at the position of 1mm from the package

ELECTRO-OPTICAL CHARACTERISTICS

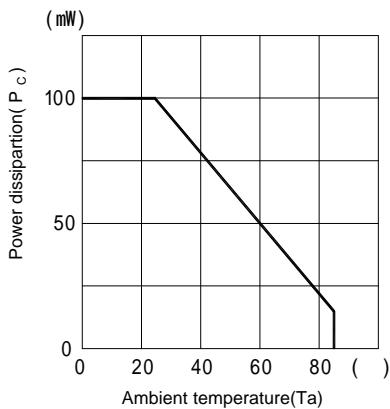
(Ta=25 °C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward Voltage	V _F	I _F =20mA	-	1.2	1.7	V
	Reverse Current	I _R	V _R =5V	-	-	10	μA
	Capacitance	C _T	f=1KHz	-	25	-	pF
	Peak Wavelength	? _P		-	940	-	nm
Output	Dark Current	I _{CEO}	V _{CE} =5V, 0 Lux	-	-	10	μA
Coupled	Light Current	I _L	V _{CE} =5V, I _F = 20mA (Non-shading)	0.5	-	15	mA
	Collector Emitter Saturation Voltage	V _{CE(SAT)}	I _F =20mA, I _C =0.1mA	-	-	0.4	V
	Response Time	tr	V _{CC} =5V, I _C =2mA, R _L =100	-	5	-	μs
	Rise Time	tr		-	5	-	μs
	Fall Time	tf		-	5	-	μs

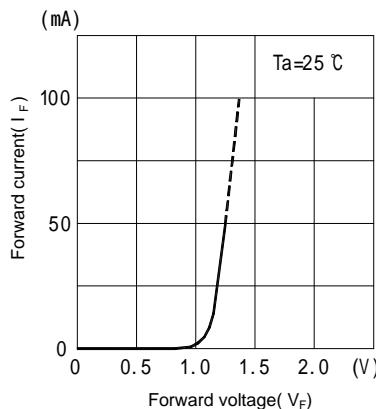
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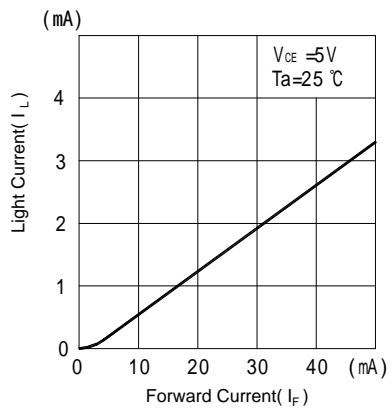
**Collector power dissipation Vs.
Ambient temperature**



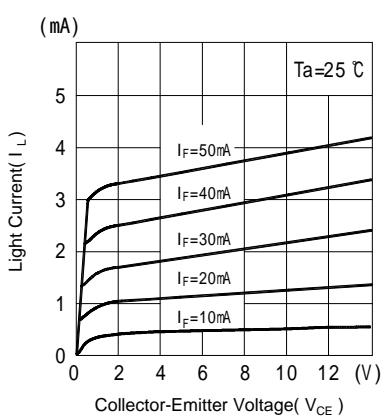
**Forward current Vs.
Forward voltage**



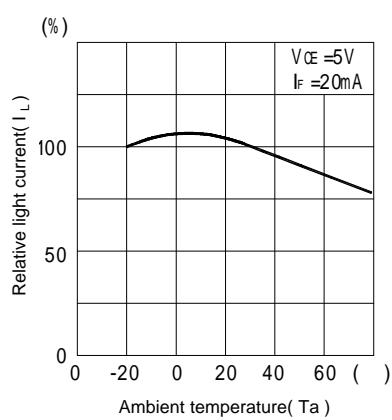
**Light current Vs.
Forward current**



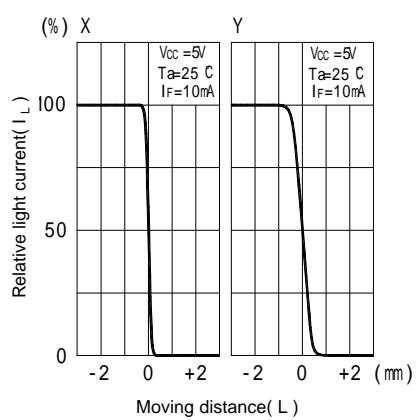
**Light current Vs.
Collentor-Emitter voltage**



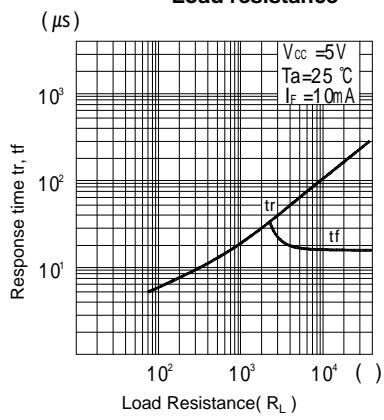
**Relative light current Vs.
Ambient temperature**



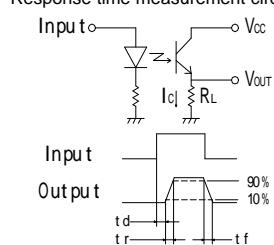
**Relative light current Vs.
Moving distance**



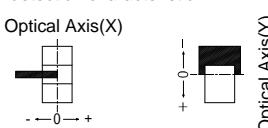
**Switching time Vs.
Load resistance**



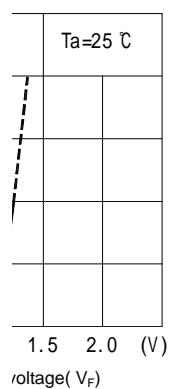
Response time measurement circuit



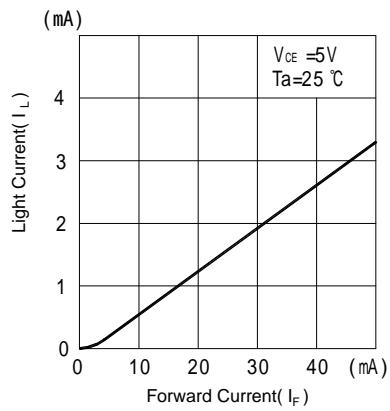
**Method of measuring position
detection characteristic**



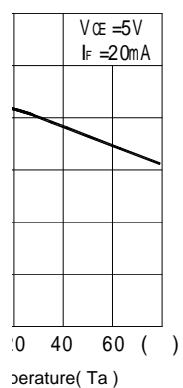
**d current Vs.
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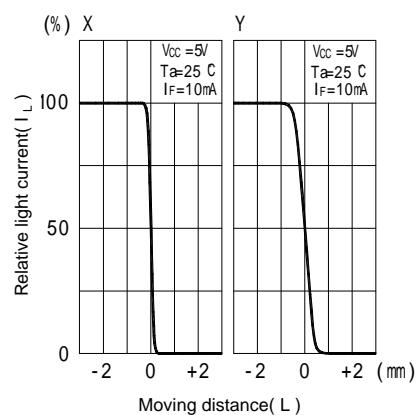
**Light current Vs.
Forward current**



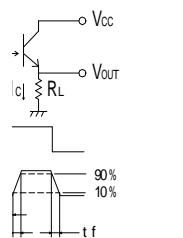
**Light current Vs.
t temperature**



**Relative light current Vs.
Moving distance**



Measurement circuit



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